- TuTovial-I Problemi

The Parameters are hie = 11001, hre = 2.5x104, hre = 50, hoe 2 yes, Compute the current gain AI, voltage gain Av, overall current gain heb overall voltage gain Avs, input impedance Ri, other put impeda AI Zo, and the operating Power gain Ap.

Soli-curvent AI = -hpe / 1+hoeiRL = -50 / 1+(25x106) x2000 = -47.6

Input impedance Ri = hie + hre Az Rz = 1100+(2.5x104) (-47.4) 2000 =

Voltage gain $A_V = \frac{A_I R_I}{R_i} = \frac{-47.6 \times 2000}{1076} = -88.47$

Overall Wolfage gain $A_{VS} = \frac{A_{V}R_{i}}{R_{i} + R_{S}} = \frac{(-88.47) \times 1076}{1076 + 800} = -50.75$

Overall Current gain $A_{IS} = \frac{A_I R_S}{R_1 + R_S} = \frac{-47.6 \times 800}{10.76 + 800} = -20.30$

output admittance

Hence 7

 $Z_0 = \frac{1}{V_0} = \frac{10^6}{18.42} = 0.0543 \times 18_2 = 54.3 \text{ kg}$

Powergain Ap=Av.A_ = 88.47x47.6 = 4211

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A transistor in CB Configuration is driven by a Voltage source. Vs of internal resistance Rs = 80012, The load impedance is a resistor Rt = 200012. The h-Parameters are his = 2212, hrs = 31104 hrs = -0.98 and hob = 0.544/v. Compute the current gain Az, input resistance Ri, Voltage gain Av, overall voltage gain Avs, overall voltage gain Avs, overall current gain Aus, overall current gain As, overall voltage gain Avs, overall voltage gain Avs, overall voltage gain

Current gain
$$A_{I} = \frac{-h\rho_{b}}{1+h_{0b}\cdot R_{L}} = \frac{-(-0.98)}{1+(0.5 \times 10^{-b}) \times 2000} = 0.98$$

Input impedance Ri = hib+hyb Az Re = 22+3x104 x0-98x2000

Voltage gain
$$A_V = \frac{A_Z \cdot R_L}{R_1} = \frac{0.98 \times 2000}{22.59} = 86.78$$

Overall voltage gain
$$A_{VS} = \frac{A_{V} \cdot R_{i}}{R_{i} + R_{5}} = \frac{86.78 \times 22.59}{22.59 + 800} = 2.383$$

Overall current gain
$$A_{IS} = \frac{A_{I} \cdot R_{S}}{R_{i} + R_{S}} = \frac{0.98 \times 800}{22.59 + 800} = 0.953$$

$$= (0.5 \times 10^{6}) - \frac{(-0.98) \times 3 \times 10^{4}}{22 + 800} = 0.8576 \times 10^{6}$$

Hence
$$Z_0 = \frac{1}{V_0} = \frac{10^6}{0.8576} \Omega = 1.166 \times 10^6 \Omega$$

Power gain Ap=Av.AI = 86.78x0.98 = 85.04.

3) A CC of transistor amplifier is driven by a voltage source of internal resistance Rs=8002 The load impedance is a resist Rz=20002. The h-Parameters are hic=11002, hrc=11002 !

hpc=-51 & hoc=25MA/V. Compute Az, Ri, Av, Avs, Az, Zo, Ap.

Current gain
$$A_{I} = \frac{-h\rho_{C}}{1+ho_{C}R_{L}} = \frac{-(-51)}{1+(25\times10^{6}\times2000)}$$

$$= \frac{51}{1.05} = 48.57$$

Input impedance R; = h;c+hyc·A_I'RL = 1100+ (1+48,57 * 2000) = 98, 240sl

Overall voltage gain
$$A_{VS} = \frac{A_{V} \cdot R_{i}}{R_{1} + R_{S}} = \frac{6.988 \times 98,240}{98,240 + 800} = 0.981$$

Overall current gain
$$A_{IS} = \frac{A_{I} \cdot R_{S}}{R_{i} + R_{S}} = \frac{48.57 \times 800}{98,240 + 800} = 0.3923$$

output admittance Yo = hoc - hec'hoc

$$y_0 = h_{0c} - \frac{h_{fc} \cdot h_{fc}}{h_{ic} + R_S}$$

 $= (25 \times 10^{-6}) - (-51)(1) = 26.86 \times 10^{35}$ Hence output impedance

$$Z_6 = \frac{1}{Y_0} = \frac{10^3}{26.86} \Omega = 37.28 \Omega$$

Power gain Ap = Az. Av = 48.57 x 0.9888 = 48.04

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Approximate Conversion Roymulas Bor Hybrid Parameters

The expression for CE Parameters interms of the CB Parameters may be obtained from Table given below by interchanging the Subscripts bee

GE		<u>CB</u>
hie	hic = hie	hib= hie 1+hpe
hpe	$h\rho_c = -(1+h\rho_e)$	$h_{Pb} = -\frac{h_{Pe}}{1 + h_{Pe}}$
hre	$h_{\gamma C} = 1$	hyb = hie hoe - hye
hoe	hoc = hoe	hob = hoe 1+hee

Three derivati formula

In exam CE, CB, CC Con be written an

CB

CE

AI = he

I thought

Ithought

Yo = hoe - hve he

hie + Rs

Avs = Avzi

Zi+Rs

Avs = Avzi